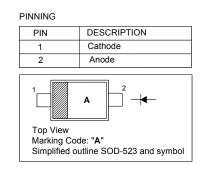
# **High Speed Switching Diode**



#### Absolute Maximum Ratings (T<sub>a</sub> = 25 °C)

| Parameter                           |                                 | Symbol           | Value         | Unit |
|-------------------------------------|---------------------------------|------------------|---------------|------|
| Repetitive Peak Reverse Voltage     |                                 | V <sub>RRM</sub> | 85            | V    |
| Reverse Voltage                     |                                 | V <sub>R</sub>   | 75            | V    |
| Continuous Forward Current          |                                 | I <sub>F</sub>   | 250           | mA   |
| Repetitive Peak Forward Current     |                                 | I <sub>FRM</sub> | 500           | mA   |
| Non-Repetitive Peak Forward Current | t = 1 µs<br>t = 1 ms<br>t = 1 s | I <sub>FSM</sub> | 4<br>1<br>0.5 | A    |
| Power Dissipation                   |                                 | P <sub>tot</sub> | 150           | mW   |
| Junction Temperature                |                                 | Tj               | 150           | °C   |
| Storage Temperature Range           |                                 | T <sub>stg</sub> | - 65 to + 150 | °C   |

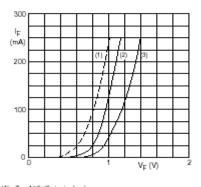
### Characteristics at $T_a = 25 \ ^{\circ}C$

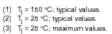
| Parameter   | Symbol           | Max.                       | Unit                 |
|---|------------------|----------------------------|----------------------|
| Forward Voltage<br>at $I_F = 1 \text{ mA}$<br>at $I_F = 10 \text{ mA}$<br>at $I_F = 50 \text{ mA}$<br>at $I_F = 150 \text{ mA}$         | V <sub>F</sub>   | 715<br>855<br>1000<br>1250 | mV                   |
| Reverse Current<br>at $V_R = 25 V$<br>at $V_R = 75 V$<br>at $V_R = 25 V$ , $T_J = 150 \circ C$<br>at $V_R = 75 V$ , $T_J = 150 \circ C$ | I <sub>R</sub>   | 30<br>1<br>30<br>50        | nA<br>μA<br>μA<br>μA |
| Diode Capacitance<br>at $V_R = 0 V$ , f = 1 MHz   | C <sub>tot</sub> | 1.5                        | pF                   |
| Reverse Recovery Time at I <sub>F</sub> = 10 mA to I <sub>R</sub> = 10 mA, I <sub>R</sub> = 1 mA, R <sub>L</sub> = 100 $\Omega$         | t <sub>rr</sub>  | 4                          | ns                   |

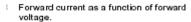


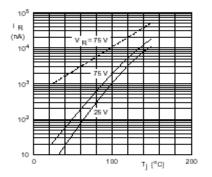


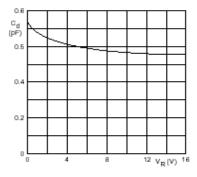












Dotted line: maximum values. Solid lines: typical values.

Reverse current as a function of junction temperature.

f = 1 MHz; T<sub>i</sub> = 25 °C.

Diode capacitance as a function of reverse voltage; typical values.







Dated : 07/04/2009

## PACKAGE OUTLINE

#### Plastic surface mounted package; 2 leads

ALL ROUND ∢ ()  $\mathsf{H}_\mathsf{E}$ D -(A) q ш С V Е UNIT D  $H_{E}$ А bp \_ 0.70 0.60 0.4 0.135 1.25 0.85 1.7 0.1 5° mm 0.3 0.127 1.15 0.75 1.5







Dated : 07/04/2009

SOD-523